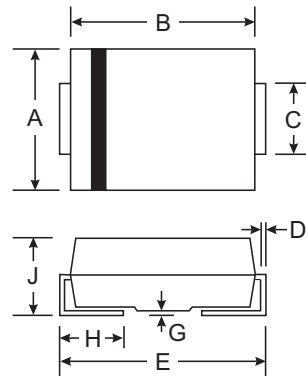
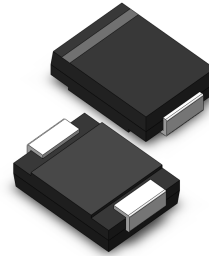


**VOLTAGE RANGE: 50-1000V**  
**CURRENT: 3.0 A**

### Features

- Glass Passivated Die Construction
- Fast Recovery Time for High Efficiency
- Low Forward Voltage Drop and High Current Capability
- Ideally Suited for Automatic Assembly
- Plastic Material: UL Flammability Classification Rating 94V-0



SMC/DO-214AB		
Dim	Min	Max
A	5.59	6.22
B	6.60	7.11
C	2.75	3.18
D	0.15	0.31
E	7.75	8.13
G	0.10	0.20
H	0.76	1.52
J	2.00	2.62
All Dimensions in mm		

### Mechanical Data

- Case: SMC/DO-214AB, Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.21 grams (approx.)

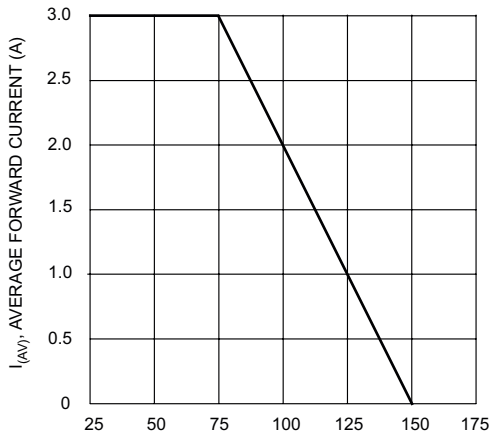


### Maximum Ratings and Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise specified

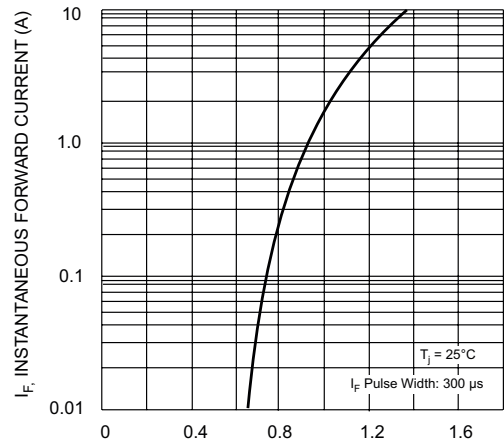
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SMF301C	SMF302C	SMF303C	SMF304C	SMF305C	SMF306C	SMF307C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Average Rectified Output Current @ $T_T = 75^\circ\text{C}$	$I_O$	3.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load (JEDEC Method)	$I_{FSM}$	100							A
Forward Voltage @ $I_F = 3.0\text{A}$	$V_{FM}$	1.3							V
Peak Reverse Current @ $T_A = 25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A = 125^\circ\text{C}$	$I_{RM}$	5.0 250							$\mu\text{A}$
Maximum Recovery Time (Note 3)	$t_{rr}$	150				250	500		ns
Typical Junction Capacitance (Note 2)	$C_j$	50							pF
Typical Thermal Resistance Junction to Terminal (Note 1)	$R_{\theta JT}$	25							K/W
Operating and Storage Temperature Range	$T_j, T_{STG}$	-65 to +150							$^\circ\text{C}$

- Notes:
1. Thermal resistance: junction to terminal, unit mounted on PC board with 5.0 mm<sup>2</sup> (0.013 mm thick) copper pad as heat sink.
  2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
  3. Reverse recovery test conditions:  $I_F = 0.5\text{A}$ ,  $I_R = 1.0\text{A}$ ,  $I_{rr} = 0.25\text{A}$ . See figure 5.



$T_T$ , TERMINAL TEMPERATURE (°C)  
Fig. 1 Forward Current Derating Curve



$V_F$ , INSTANTANEOUS FORWARD VOLTAGE (V)  
Fig. 2 Typical Forward Characteristics

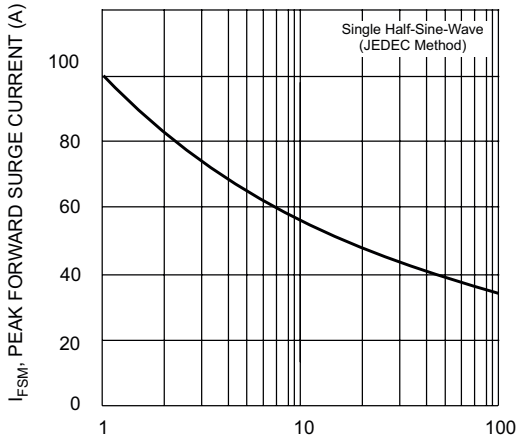


Fig. 3 Forward Surge Current Derating Curve

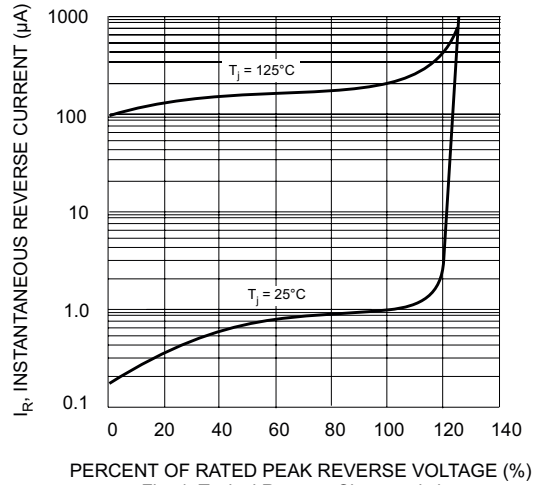
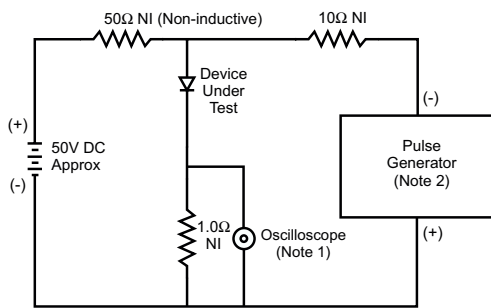
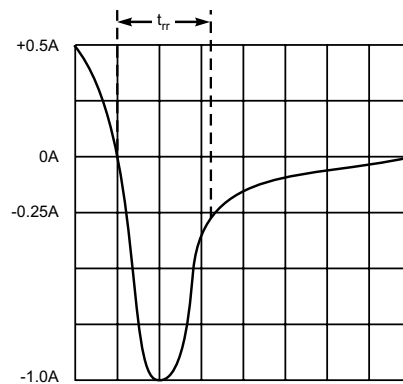


Fig. 4 Typical Reverse Characteristics



Notes:  
1. Rise Time = 7.0ns max. Input Impedance = 1.0M $\Omega$ , 22pF.  
2. Rise Time = 10ns max. Input Impedance = 50 $\Omega$ .



Set time base for 50/100 ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit